
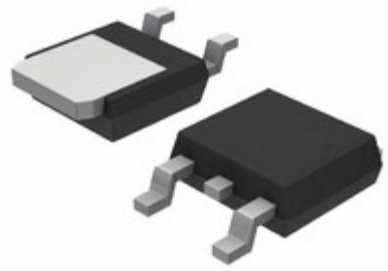
	<h2 style="color: red;">NDD01N60T4G</h2>
	<p>Hersteller-Teilenummer: NDD01N60T4G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 600V 1.5A DPAK</p> <hr/> <p>Datenblätter:  NDD01N60T4G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 11700 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

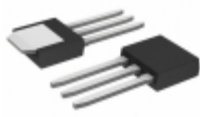
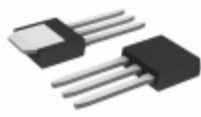



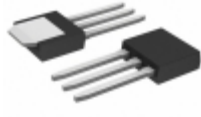
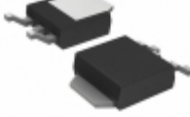
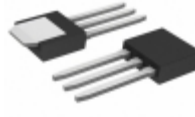
Spezifikationen

Teilenummer	NDD01N60T4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 600V 1.5A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	11700 pcs Stock
VGS (th) (Max) @ Id	3.7V @ 50µA
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	DPAK
Serie	-
Rds On (Max) @ Id, Vgs	8.5 Ohm @ 200mA, 10V
Verlustleistung (max)	46W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	160pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	7.2nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.5A (Tc)

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Sie können auch interessiert

<p>sein:</p>  <p>NDD02N60Z-1G ON Semiconductor MOSFET N-CH 600V IPAK</p>	 <p>NDD03N40Z-1G ON Semiconductor MOSFET N-CH 400V 2.1A IPAK-4</p>	 <p>NDD02N60Z ON NDD02N60Z ON</p>	 <p>NDD02N40T4G ON Semiconductor MOSFET N-CH 400V 1.7A DPAK</p>
 <p>NDD01N60 O O DPAK</p>	 <p>NDD02N40-1G ON Semiconductor MOSFET N-CH 400V 1.7A IPAK</p>	 <p>NDD02N60ZT4G ON Semiconductor MOSFET N-CH 600V DPAK</p>	 <p>NDD01N60-1G ON Semiconductor MOSFET N-CH 600V 1.5A IPAK</p>

Verwandtes Hot-Keyword

Mehr

NDD01N60T4G AMI Semiconductor / ON Semiconductor	NDD01N60T4G Datenblatt	NDD01N60T4G-Datenblätter	NDD01N60T4G PDF	AMI Semiconductor / ON Semiconductor NDD01N60T4G
NDD01N60T4G Electronic	NDD01N60T4G-Komponenten	NDD01N60T4G-Verteiler	NDD01N60T4G-Bild	NDD01N60T4G-Teil
NDD01N60T4G Preis	NDD01N60T4G Hersteller	NDD01N60T4G Bild	NDD01N60T4G Aktie	NDD01N60T4G Inventar
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